

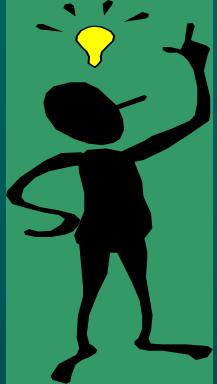
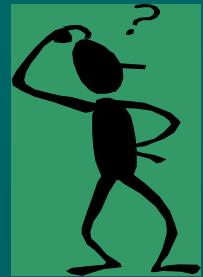
Moisture Diffusion in Molding Compounds and Quality Assurance of PEMs for Space Applications

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No humidity in space. Why moisture concerns?

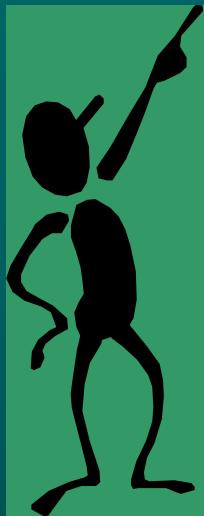


We need to assure that no moisture related failures occur during the ground phase integration and testing period (2 to 5 years).

Quality assurance strategy for PEMs:

- **Moisture prevention**
- **Adequate qualification testing**

Quality assurance strategy for PEMs for military and space applications



Moisture prevention strategy:

- **Military applications:** Wafer Applied Seal for PEM Protection (WASPP);
- **Space applications:** Virtual monitoring/simulation of the moisture level variations and baking of components and assemblies.

Adequate testing:

- **Military applications:** To assure reliability for 15 to 20 years of storage and operation in harsh humid environments.
- **Space applications:** To assure reliability for 5 years maximum in controlled laboratory conditions.

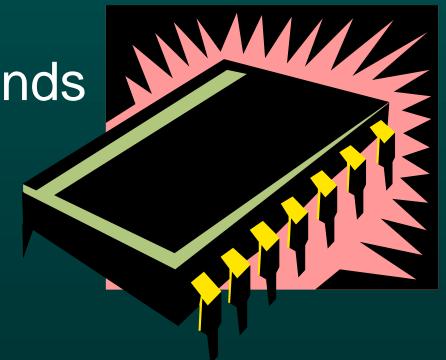
Purpose and Outline

The purpose is to discuss:

- ◆ Moisture characteristics of MCs and how they can be used for the moisture prevention strategy and for development of adequate testing.
- ◆ The relevance of HAST for PEMs intended for space applications.

Outline:

- ◆ **Part I:**
 - Bake-out conditions for PEMs;
 - Diffusion characteristics of molding compounds
- ◆ **Part II:**
 - Acceleration factors of HAST.
 - What might be an adequate testing?



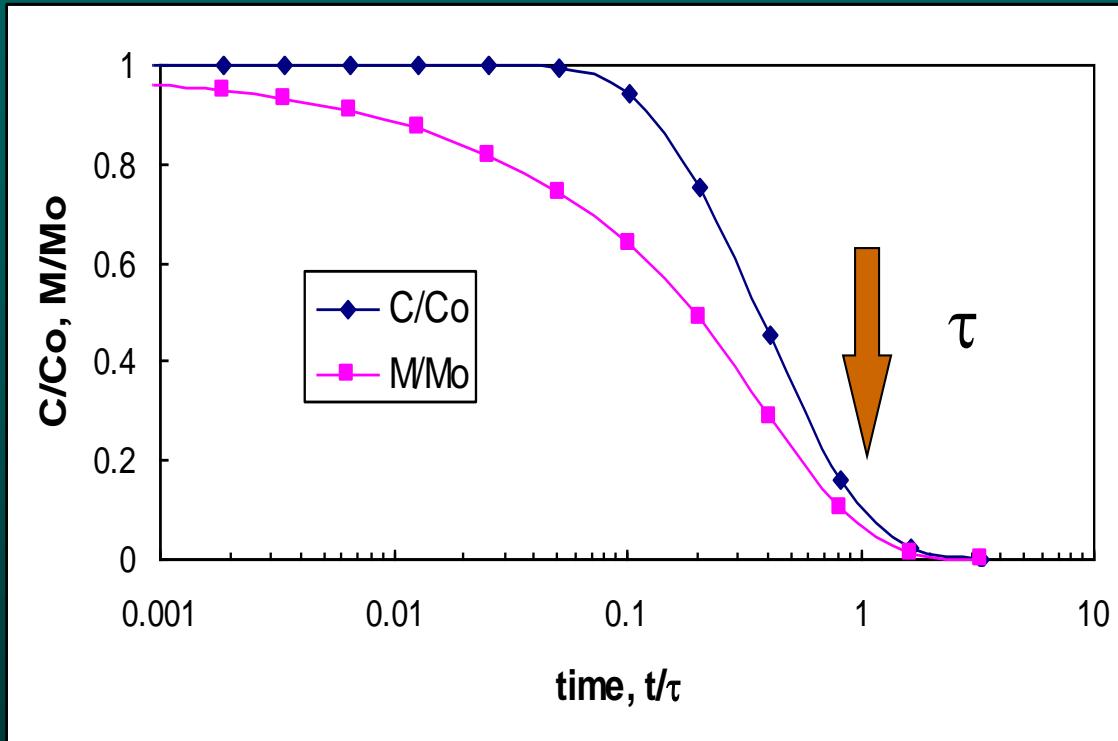
Part I. Moisture Diffusion Characteristics and Their Measurement

The first step in any MC or PEM degradation process is moisture diffusion.

→ The characteristic times of diffusion are important for implementing the moisture prevention strategy.

Characteristic times of moisture diffusion in plastic encapsulated parts

The master curve for moisture diffusion



Bake-out time:
$$\tau(T) = h^2/D(T)$$

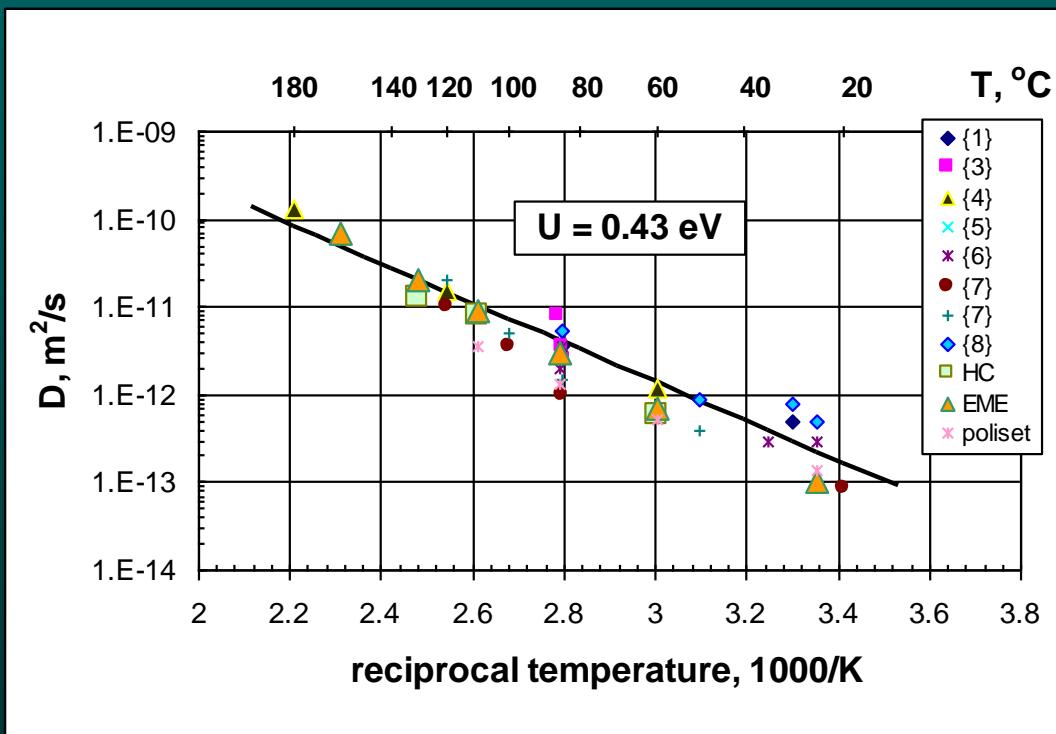
2h – package thickness

At $t = \tau \Rightarrow$
 $C/Co=0.1,$
 $M/Mo=0.06$

Moisture concentration at the die surface and mass losses of a flat package with rated baking time.

Diffusion characteristics of epoxy encapsulating materials

Data reported in literature.



D_{85} varies ~ 10 times

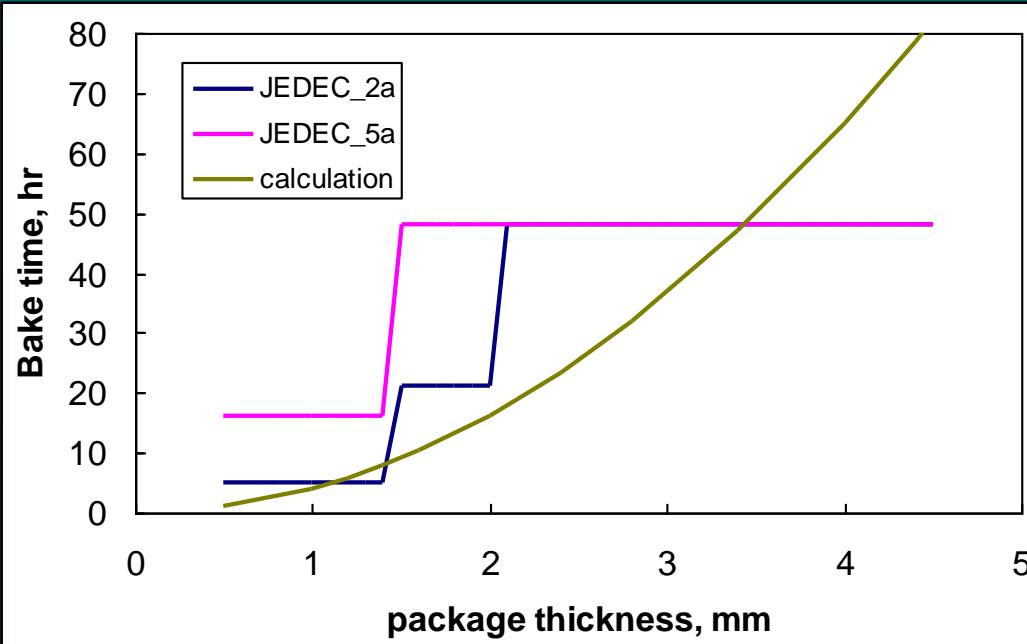
$$D = D_o \exp(-U / kT)$$

Averaged characteristics of MC:

$$D_o = 7.35 \times 10^{-6} \text{ m}^2/\text{sec}$$

$$U = 0.43 \text{ eV}$$

Calculated bake times at 125 °C and JEDEC recommendations



- Ignoring real size of the parts causes significant errors.
- JEDEC is focused on SMT reflow soldering and might be not adequate for moisture control purposes.

Three body thickness groups per
IPC/JEDEC J-STD-033A, July 2002:
<1.4 mm; <2 mm; < 4.5 mm

IPC-SM-786A, '95: < >2 mm

Note:

- 2a and 5a are levels of moisture sensitivity.
- part saturated at 30 °C/85% RH

In-situ non-isothermal technique for D(T) measurements

A. Teverovsky, "A Rapid Technique for Moisture Diffusion Characterization of Molding Compounds in PEMs",
<http://nepp.nasa.gov>

Areas of application

- Moisture sorption simulation (virtual monitoring of moisture level).
- Calculation of bake-out conditions.
- Lot characterization of molding compound.
(ROBOCOTS: need rapid assessment methods)
- Evaluation of moisture leaks along the leads of a plastic package.
- Development of adequate moisture stress testing (HAST alternative).

Part II. Highly Accelerated Stress Test (HAST)

**Do we need to use same environmental
stress testing as for PEMs intended for
harsh humid conditions?**

Accelerated moisture resistance tests

- **JESD22-A102-C (unbiased autoclave):**

121 °C, 100% RH, 24 to 336 hrs (96 hr typical).

- **JESD22-A118 (unbiased HAST):**

Cond. A: 130 °C, 85% RH, 96 hrs.

Cond. B: 110 °C, 85% RH, 264 hrs.

- **JESD22-A110-B (biased HAST):**

Cond. A: 130 °C, 85% RH, 96 hrs.

Cond. B: 110 °C, 85% RH, 264 hrs.

Equivalent
to 1000
hours at
85 °C and
85% RH

Typical HAST conditions: bias at 130 °C, 85% RH

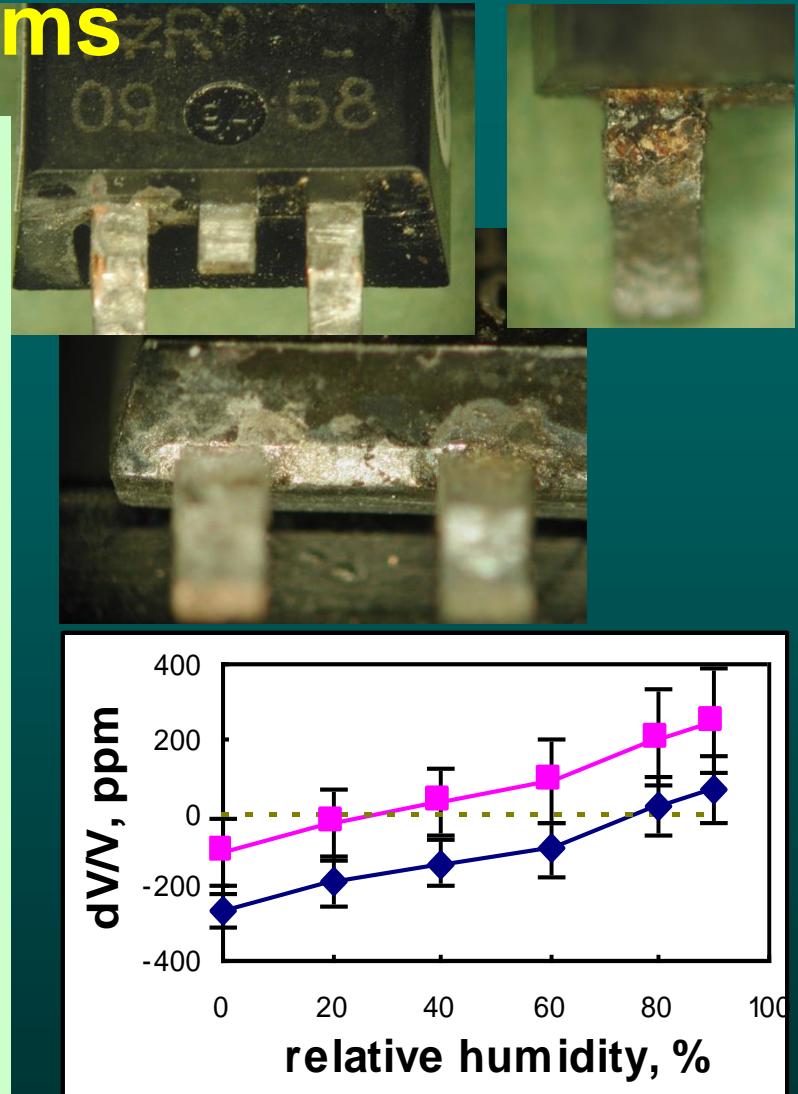
- 96 hrs per JESD22-A110-B.
- 150 hrs per NAVSEA SD18 (Part Requirement & Application Guide).
- 500 hrs per PRF38535 spec. (for technology characterization).

NASA projects: 250 hrs?

HAST failure mechanisms

Package level

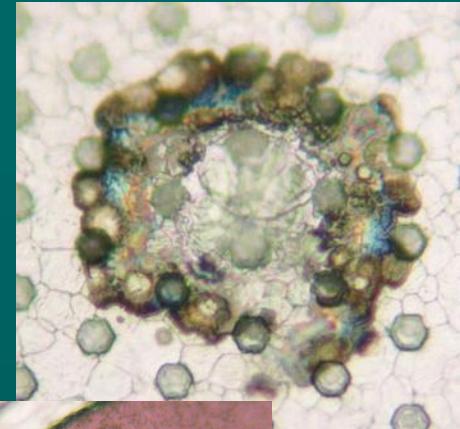
- Corrosion of the leads.
- Dendrite formation (on the surface and inside packages).
- Swelling/shrinkage:
 - ✓ Delaminations;
 - ✓ Solder ball failures in PBGA and flip-chip technology;
 - ✓ warpage of large packages;
 - ✓ parametric shifts in linear devices.



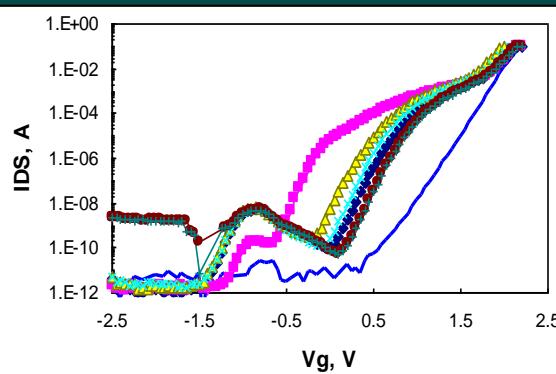
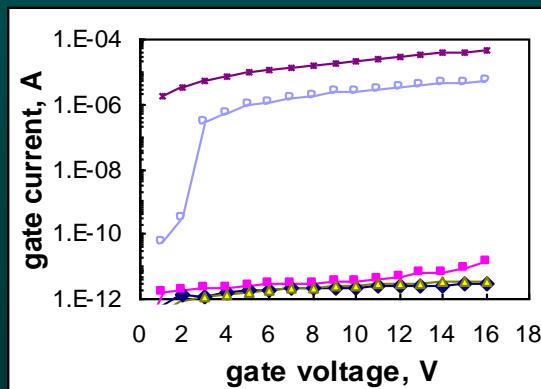
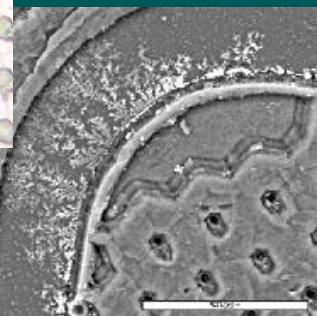
HAST failure mechanisms

Die level:

- Corrosion of Al metallization.
- Dendrites between metallization lines.
- Leakage currents.
- Charge instability (lateral, ion drift, hot electron).



Curtesy of
C.Greenwell



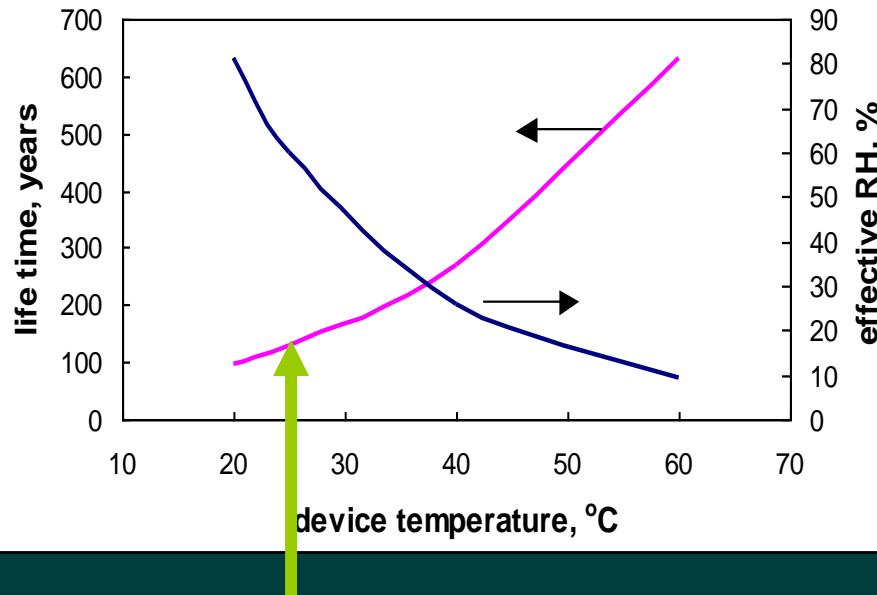
HEXFET failures

Mechanisms of moisture induced parametric degradation require additional analysis



What is the HAST acceleration?

Life time at 25 °C/ 60% ambient conditions
equivalent to HAST: 130°C/85% 100 hrs)



Life time increases with
device temperature

Best-fit model:
S. Peck [86];
Hallberg and Peck [91];
S. Tam [95]; SSB-1 [2000];
J. Sweet [02]:

$$t_f = A(RH)^{-n} \exp\left(\frac{E_a}{kT}\right)$$

$$0.7 < E_a < 1.1 \text{ eV}; \\ 1 < n < 5$$

$$E_a = 0.8 \text{ eV}; \quad n = 2.7$$

$$RH_{eff} = RH_a \times \frac{P_s(T_a)}{P_s(T_{dev})}$$

Test results on linear devices

11 part types out of 25 failed HAST

HAST: 130 °C, 85% RH, 250 hours

Part	DC	Pack. type	QTY tested	QTY failed	Failure mode
Vref	0112	SOIC8	31	3	1- increased V_{out} 2 - catastrophic
Opamp	0101	SOIC16	30	2	-
Instr. amp	0033	SOIC8	30	30	Excessive input currents
FET1	0041	SOT223	29	28	I_{DS} , V_{GTH}
FET2	0040	D ² Pak	30	29	~ 60% parametric shift

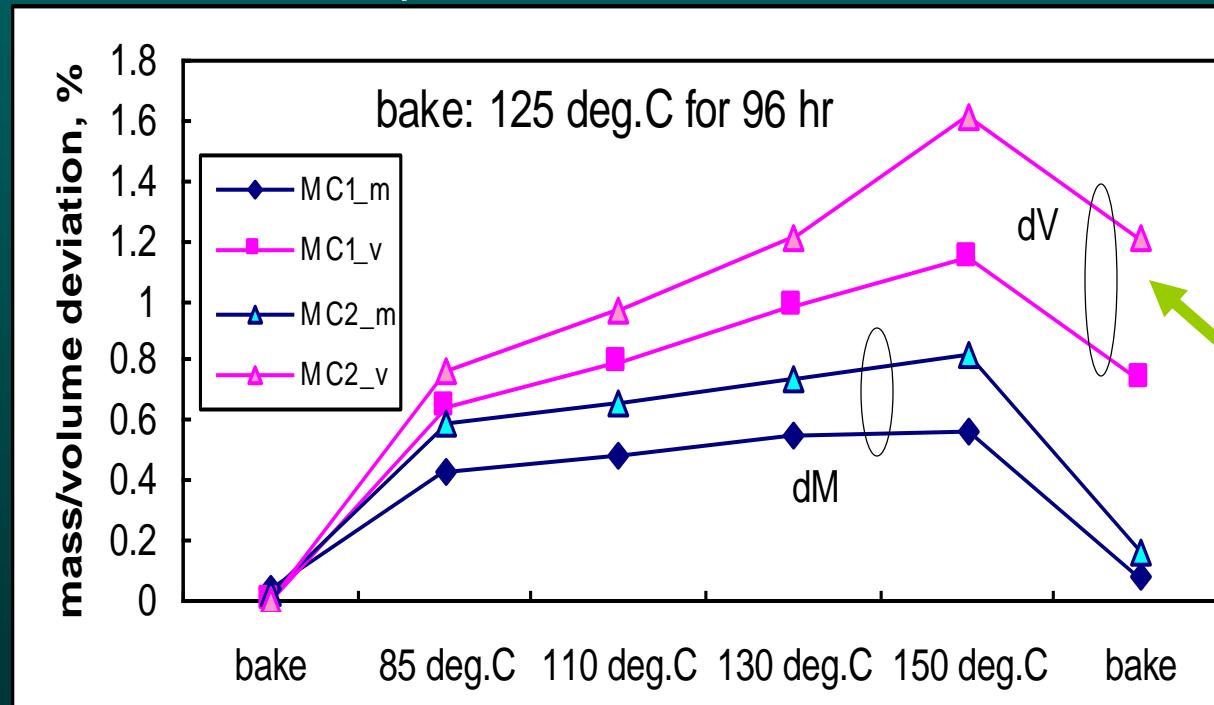
Is HAST adequate for normal conditions?

- ◆ Testing temperature (130 °C) is above the operational range for many parts.
- ◆ Degradation of molding compound:
 - Decrease of Tg (up to 100 °C in resins and up to 30 °C in MCs).
 - Enhanced creep.
 - Decrease of the tensile stress and adhesion.
- ◆ The model accelerates mostly corrosion failures, but corrosion is no longer a prime concern.
- ◆ Moisture assisted hot-carrier degradation might have $U < 0$.

Irreversible changes in MCs: An example

Test: moisture uptake and swelling after HAST were measured on two epoxy molding compounds.

Conditions: saturation with moisture at 85% RH and different temperatures.



Additional mechanical stresses due to swelling:

$$\sigma \approx A \times E \times [(\alpha_{MC} - \alpha_{LF}) \times \Delta T + \beta \times \Delta m],$$

At $\alpha_{MC} \approx \alpha_{LF}$ mechanical stresses are due only to moisture sorption.

An increase in volume might cause delaminations and mechanical failures.

Do we need moisture testing?

Ionic dissociation in polymer:

Charge carriers are impurity ions generated by dissociation of a salt MA

The equilibrium constant:

n_o is the concentration of salt molecules; f is the fractional degree of dissociation

In a medium with low ϵ :

U_0 is the energy of ions separation in vacuum



$$K = \frac{[M^-] \times [A^-]}{M^+ A^-} = \frac{f^2 n_o}{1-f}$$

$$K = K_0 \times \exp\left(\frac{U_0}{\epsilon \times kT}\right)$$

1. Moisture concentration at the die surface at RT is approximately the same as at high T/RH conditions.

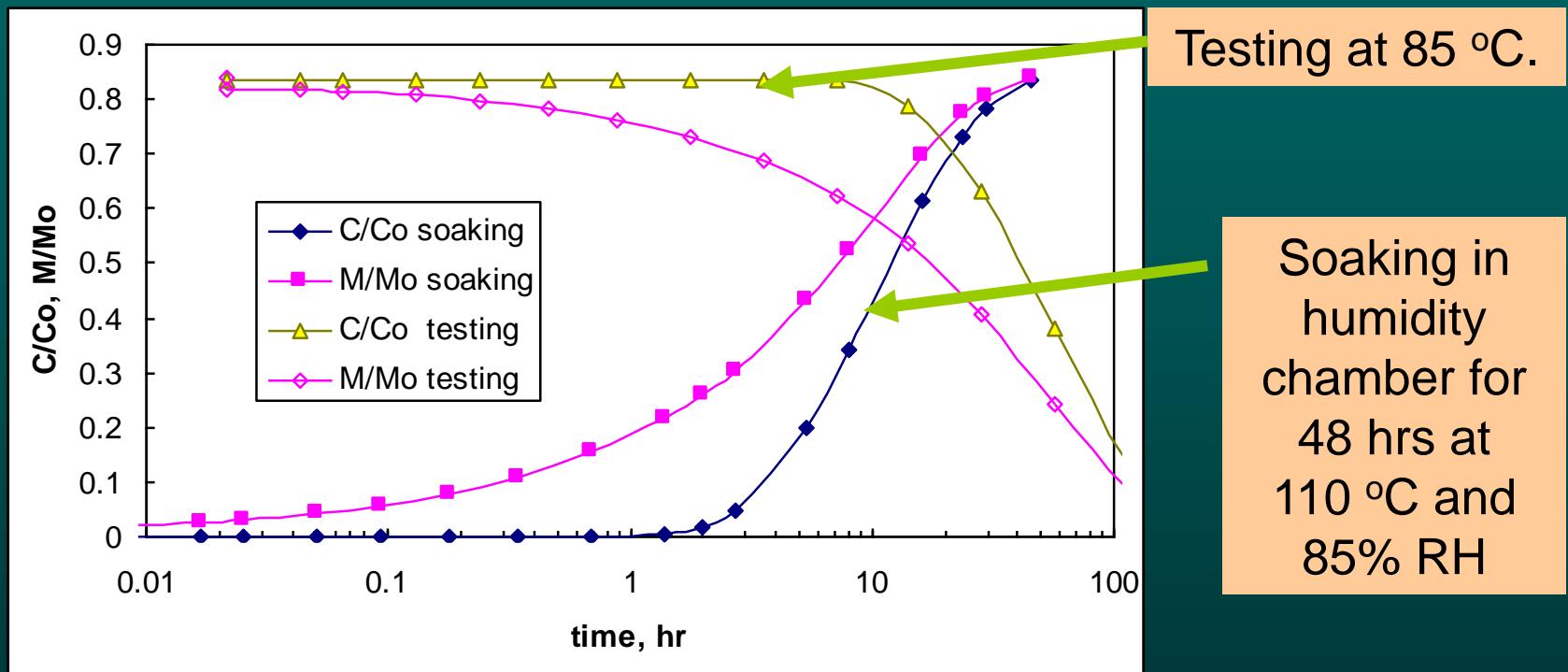
$$n = A \exp\left(\frac{U_0}{2\epsilon \times kT}\right)$$

$$\epsilon_{mc} = \epsilon_{mc}^0 + \delta m_{mc} \times \epsilon_w \times \frac{\tilde{\rho}_{mc}}{\tilde{\rho}_w}$$

2. Another reason: Moisture activates ionic impurities similar to temperature. Moisture testing might accelerate degradation mechanisms related to charge instability.

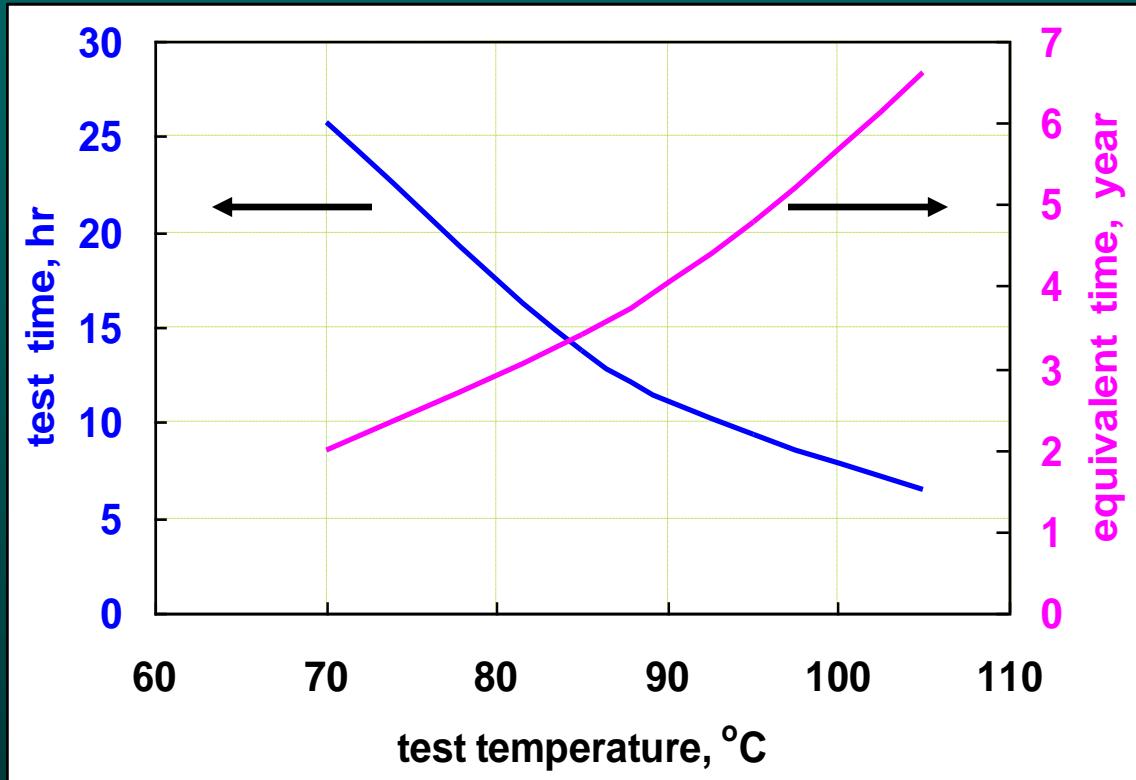
A possible alternative to HAST: MS + HTB

Moisture evolution in a 2 mm thick package



Note: $C/C_o = 1$ corresponds to the equilibrium moisture saturation at 100% RH.

Calculated test time and equivalent time of operation



Package thickness 2 mm

Soaking conditions:

$\text{RH} = 95\%$,
 $T = 110\text{ }^{\circ}\text{C}$,
 $t = 30\text{ hr}$

Test conditions:

$\text{RH}_{\text{eff}} \geq 90\%$
 $70\text{ }^{\circ}\text{C} < T < 105\text{ }^{\circ}\text{C}$

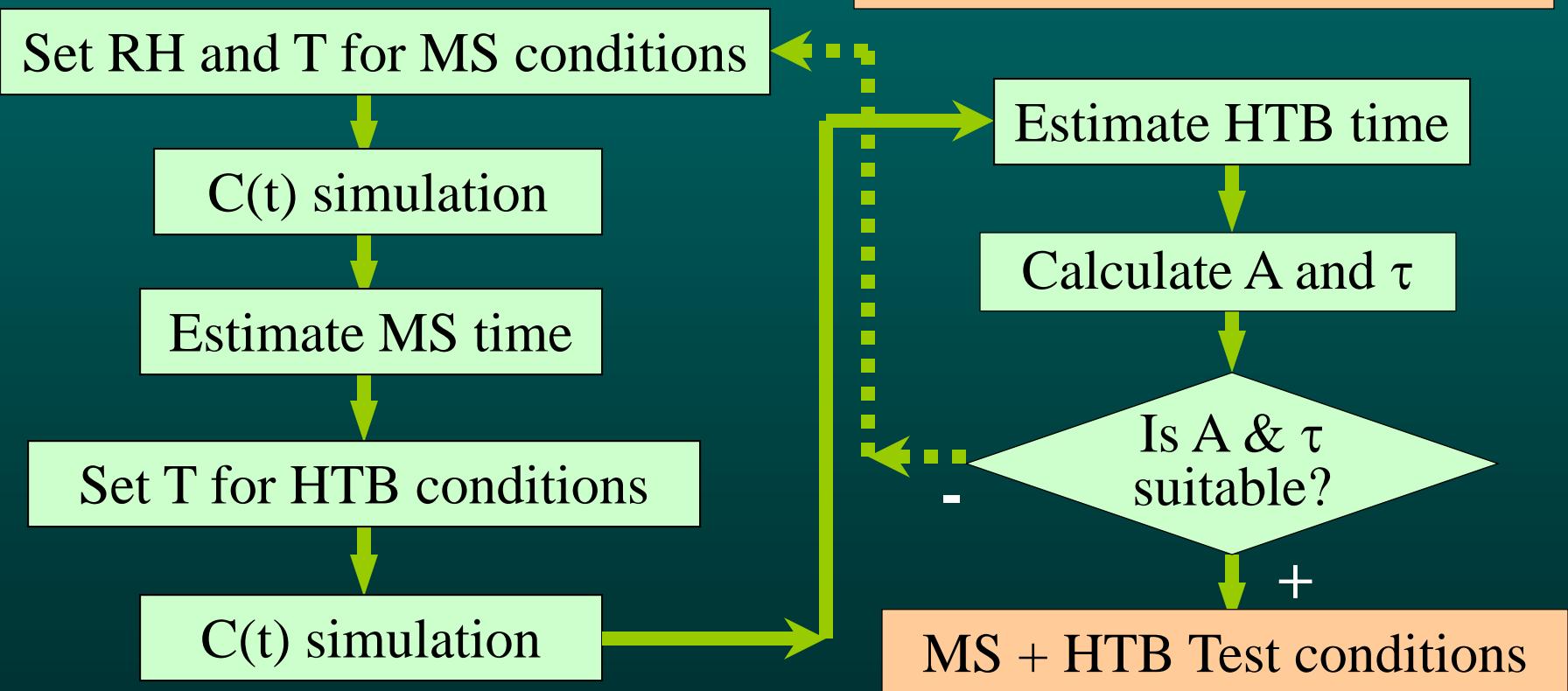
Operating conditions (environment):

$\text{RH} = 50\%$
 $T = 20\text{ }^{\circ}\text{C}$

HAST alternative: MS + HTB testing

Algorithm for calculation of MS+HTB testing conditions

Input: Package size; D(T) data; ground phase conditions; maximum storage and operation temperatures.



Conclusion

- ◆ Suggested quality assurance strategy: moisture content control (virtual monitoring and baking) + adequate testing.
- ◆ The moisture prevention strategy can be implemented by assessment of moisture content and calculations of the bake-out conditions based on D(T) data.
- ◆ The existing HAST conditions are too harsh for PEMs intended for space applications. A possible alternative to HAST might be MS + HTB testing.
- ◆ Additional analysis of moisture induced parametric degradation and acceleration factors is necessary.